

Title (en)
THERMAL INTERFACE MATERIALS AND METHODS FOR PROCESSING THE SAME

Title (de)
WÄRMEZWISCHENSCHICHTMATERIALIEN UND VERFAHREN ZU IHRER VERARBEITUNG

Title (fr)
MATÉRIAUX D'INTERFACE THERMIQUE ET PROCÉDÉS POUR LEUR TRANSFORMATION

Publication
EP 2710628 A4 20150408 (EN)

Application
EP 12785480 A 20120517

Priority
• US 201113111735 A 20110519
• US 2012038280 W 20120517

Abstract (en)
[origin: US2012292005A1] A thermal interface material is provided for use to fill a gap between surfaces in a thermal transfer system to transfer heat between the surfaces. The thermal interface material includes a base material and thermally conductive particles dispersed within the base material. The thermal interface material is conditioned under reduced pressure (e.g., prior to being placed in the gap between the surfaces, while being placed in the gap, after being placed in the gap, etc.) and, within about forty-eight hours or less of conditioning, the conditioned thermal interface material is either positioned in a container that inhibits ambient gas from contacting it (either alone or applied to the surfaces), or used to transfer heat between the surfaces. As such, the thermal interface material is substantially free of cracks following exposure to thermal cycling comprising a temperature change of at least about 100 degrees Celsius for at least about 10 cycles.

IPC 8 full level
F28F 13/00 (2006.01); **H01L 23/373** (2006.01); **H01L 23/42** (2006.01)

CPC (source: CN EP KR US)
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C-Set (source: EP US)
H01L 2924/0002 + H01L 2924/00

Citation (search report)
• [XA] US 2006275608 A1 20061207 - TONAPI SANDEEP S [US], et al
• [XA] US 2005016714 A1 20050127 - CHUNG DEBORAH D L [US]
• [XA] US 2011038124 A1 20110217 - BURNHAM KIKUE S [US], et al
• [A] US 2005256241 A1 20051117 - SACHDEV KRISHNA G [US], et al
• See references of WO 2012158876A2

Designated contracting state (EPC)
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DOCDB simple family (publication)
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